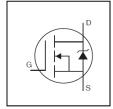
## **AUTOMOTIVE GRADE**

AUIRFR3710Z

HEXFET® Power MOSFET

#### **Features**

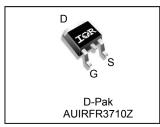
- Advanced Process Technology
- Ultra Low On-Resistance
- 175°C Operating Temperature
- Fast Switching
- · Repetitive Avalanche Allowed up to Timax
- Lead-Free, RoHS Compliant
- Automotive Qualified \*



V <sub>DSS</sub>	100V
R <sub>DS(on)</sub> max.	18mΩ
I <sub>D (Silicon Limited)</sub>	56A
D (Package Limited)	42A

## **Description**

Specifically designed for Automotive applications, this HEXFET® Power MOSFET utilizes the latest processing techniques to achieve extremely low on-resistance per silicon area. Additional features of this design are a 175°C junction operating temperature, fast switching speed and improved repetitive avalanche rating. These features combine to make this design an extremely efficient and reliable device for use in Automotive applications and a wide variety of other applications.



G	D	S
Gate	Drain	Source

Door next number   Dooks no Tune		Standard Pack		Orderable Part Number
Base part number	Package Type	Form Quantity		Orderable Part Number
AUIRFR3710Z	D. Dok	Tube	75	AUIRFR3710Z
AUIRFR3/10Z	D-Pak	Tape and Reel Left	3000	AUIRFR3710ZTRL

## **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only; and functional operation of the device at these or any other condition beyond those indicated in the specifications is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. The thermal resistance and power dissipation ratings are measured under board mounted and still air conditions. Ambient temperature (TA) is 25°C, unless otherwise specified.

Symbol	Parameter	Max.	Units	
I <sub>D</sub> @ T <sub>C</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V (Silicon Limited)	56		
I <sub>D</sub> @ T <sub>C</sub> = 100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V (Silicon Limited)	39	A	
I <sub>D</sub> @ T <sub>C</sub> = 25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V (Package Limited)	42		
I <sub>DM</sub>	Pulsed Drain Current ①	220		
$P_D @ T_C = 25^{\circ}C$	Maximum Power Dissipation	140	W	
	Linear Derating Factor	0.95	W/°C	
$V_{GS}$	Gate-to-Source Voltage	± 20	V	
E <sub>AS</sub>	Single Pulse Avalanche Energy (Thermally Limited) ②	150	m l	
E <sub>AS</sub> (Tested)	Single Pulse Avalanche Energy Tested Value ®	200	- mJ	
I <sub>AR</sub>	Avalanche Current ① See Fig.15,16, 12a, 12b		Α	
E <sub>AR</sub>	Repetitive Avalanche Energy ©		mJ	
$T_J$	Operating Junction and -55 to + 175			
T <sub>STG</sub>	Storage Temperature Range		°C	
	Soldering Temperature, for 10 seconds (1.6mm from case)	300		

### Thermal Resistance

Symbol	Parameter	Тур.	Max.	Units
$R_{\theta JC}$	Junction-to-Case ®		1.05	
$R_{\theta JA}$	Junction-to-Ambient ( PCB Mount) ⑦		50	°C/W
$R_{\theta JA}$	Junction-to-Ambient		110	

HEXFET® is a registered trademark of Infineon.

<sup>\*</sup>Qualification standards can be found at www.infineon.com



# Static @ T<sub>J</sub> = 25°C (unless otherwise specified)

	Parameter		Тур.	Max.	Units	Conditions
$V_{(BR)DSS}$	Drain-to-Source Breakdown Voltage	100			V	$V_{GS} = 0V, I_D = 250\mu A$
$\Delta V_{(BR)DSS}/\Delta T_{J}$	Breakdown Voltage Temp. Coefficient		0.088		V/°C	Reference to 25°C, I <sub>D</sub> = 1mA
R <sub>DS(on)</sub>	Static Drain-to-Source On-Resistance		15	18	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 33A ③
$V_{GS(th)}$	Gate Threshold Voltage	2.0		4.0	V	$V_{DS} = V_{GS}$ , $I_D = 250\mu A$
gfs	Forward Trans conductance	39			S	$V_{DS} = 25V, I_{D} = 33A$ ③
	Drain-to-Source Leakage Current			20		$V_{DS} = 100V, V_{GS} = 0V$
I <sub>DSS</sub>	Drain-to-Source Leakage Current			250	μA	$V_{DS} = 100V, V_{GS} = 0V, T_{J} = 125^{\circ}C$
	Gate-to-Source Forward Leakage			200	n ^	V <sub>GS</sub> = 20V
IGSS	Gate-to-Source Reverse Leakage			-200	nA	V <sub>GS</sub> = -20V

# Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise specified)

		-	-		
Total Gate Charge		69	100		I <sub>D</sub> = 33A
Gate-to-Source Charge		15		nC	$V_{DS} = 80V$
Gate-to-Drain Charge		25			V <sub>GS</sub> = 10V3
Turn-On Delay Time		14			$V_{DD} = 50V$
Rise Time		43		no	I <sub>D</sub> = 33A
Turn-Off Delay Time		53		115	$R_G = 6.8\Omega$
Fall Time		42			V <sub>GS</sub> = 10V③
Internal Drain Inductance		4.5			Between lead, 6mm (0.25in.)
Internal Source Inductance		7.5			from package and center of die contact
Input Capacitance		2930			$V_{GS} = 0V$
Output Capacitance		290			$V_{DS} = 25V$
Reverse Transfer Capacitance		180		nΕ	f = 1.0MHz
Output Capacitance		1200		рΓ	$V_{GS} = 0V$ , $V_{DS} = 1.0V$ $f = 1.0MHz$
Output Capacitance		180			$V_{GS} = 0V$ , $V_{DS} = 80V$ $f = 1.0MHz$
Effective Output Capacitance		430			$V_{GS} = 0V, V_{DS} = 0V \text{ to } 80V  $
	Gate-to-Source Charge Gate-to-Drain Charge Turn-On Delay Time Rise Time Turn-Off Delay Time Fall Time Internal Drain Inductance Internal Source Inductance Input Capacitance Output Capacitance Reverse Transfer Capacitance Output Capacitance Output Capacitance Output Capacitance Output Capacitance Output Capacitance	Gate-to-Source Charge —— Gate-to-Drain Charge —— Turn-On Delay Time —— Rise Time —— Turn-Off Delay Time —— Fall Time —— Internal Drain Inductance —— Input Capacitance —— Output Capacitance —— Reverse Transfer Capacitance —— Output Capacitance ——	Gate-to-Source Charge         —         15           Gate-to-Drain Charge         —         25           Turn-On Delay Time         —         14           Rise Time         —         43           Turn-Off Delay Time         —         53           Fall Time         —         42           Internal Drain Inductance         —         4.5           Internal Source Inductance         —         7.5           Input Capacitance         —         2930           Output Capacitance         —         180           Output Capacitance         —         1200           Output Capacitance         —         180	Gate-to-Source Charge         —         15         —           Gate-to-Drain Charge         —         25         —           Turn-On Delay Time         —         14         —           Rise Time         —         43         —           Turn-Off Delay Time         —         53         —           Fall Time         —         42         —           Internal Drain Inductance         —         4.5         —           Internal Source Inductance         —         7.5         —           Input Capacitance         —         2930         —           Output Capacitance         —         290         —           Reverse Transfer Capacitance         —         180         —           Output Capacitance         —         1200         —           Output Capacitance         —         180         —	Gate-to-Source Charge         —         15         —         nC           Gate-to-Drain Charge         —         25         —           Turn-On Delay Time         —         14         —           Rise Time         —         43         —           Turn-Off Delay Time         —         53         —           Fall Time         —         42         —           Internal Drain Inductance         —         4.5         —           Internal Source Inductance         —         7.5         —           Input Capacitance         —         2930         —           Output Capacitance         —         290         —           Reverse Transfer Capacitance         —         180         —           Output Capacitance         —         1200         —           Output Capacitance         —         180         —

## **Diode Characteristics**

21040 011	71040 0114140101101100					
	Parameter	Min.	Тур.	Max.	Units	Conditions
Is	Continuous Source Current			56		MOSFET symbol
.3	(Body Diode)			showing the		
I <sub>SM</sub>	Pulsed Source Current			220		integral reverse
	(Body Diode) ①					p-n junction diode.
$V_{SD}$	Diode Forward Voltage			1.3	V	$T_J = 25^{\circ}C, I_S = 33A, V_{GS} = 0V \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ $
t <sub>rr</sub>	Reverse Recovery Time		35	53	ns	$T_J = 25^{\circ}C$ , $I_F = 33A$ , $V_{DD} = 50V$
$Q_{rr}$	Reverse Recovery Charge		41	62	nC	di/dt = 100A/µs ③
t <sub>on</sub>	Forward Turn-On Time	Intrinsion	turn-or	time is	negligil	ble (turn-on is dominated by L <sub>S</sub> +L <sub>D</sub> )

### Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature. (See fig. 11)

- $\oplus$  C<sub>oss</sub> eff. is a fixed capacitance that gives the same charging time as C<sub>oss</sub> while V<sub>DS</sub> is rising from 0 to 80% V<sub>DSS</sub>
- © Limited by T<sub>Jmax</sub>, see Fig.12a, 12b, 15, 16 for typical repetitive avalanche performance.
- ⑥ This value determined from sample failure population, starting  $T_J = 25$ °C, L = 0.28mH, R<sub>G</sub> = 25Ω, I<sub>AS</sub> = 33A, V<sub>GS</sub> =10V.
- When mounted on 1" square PCB (FR-4 or G-10 Material). For recommended footprint and soldering techniques refer to application note #AN-994

 $\otimes$  R<sub>0</sub> is measured at T<sub>J</sub> approximately 90°C.



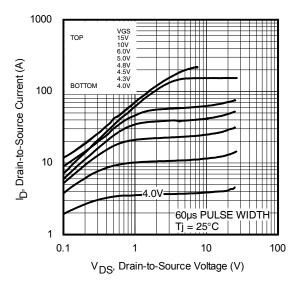
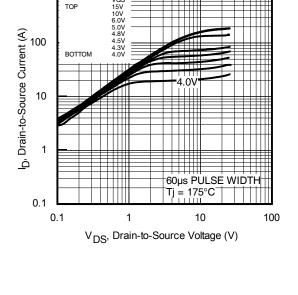


Fig. 1 Typical Output Characteristics



1000

Fig. 2 Typical Output Characteristics

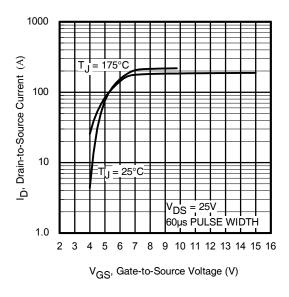
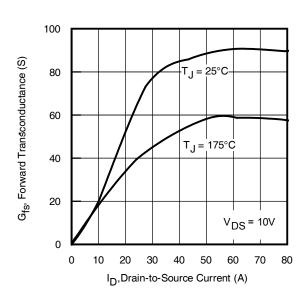
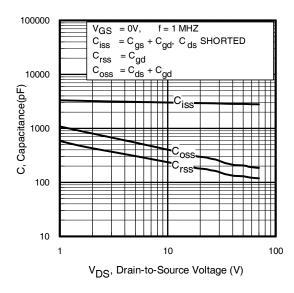


Fig. 3 Typical Transfer Characteristics

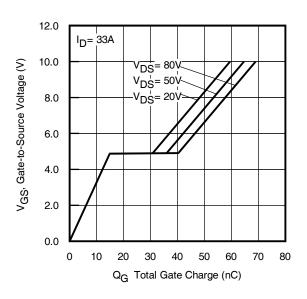


**Fig. 4** Typical Forward Trans conductance Vs. Drain Current





**Fig 5.** Typical Capacitance vs. Drain-to-Source Voltage



**Fig 6.** Typical Gate Charge vs. Gate-to-Source Voltage

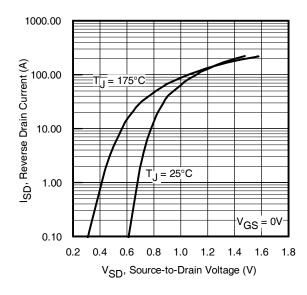


Fig. 7 Typical Source-to-Drain Diode Forward Voltage

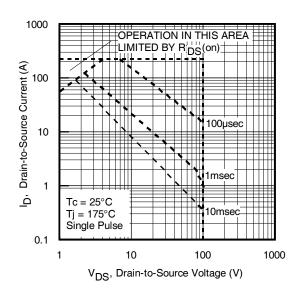
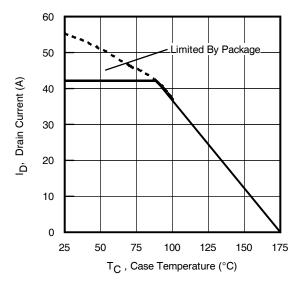
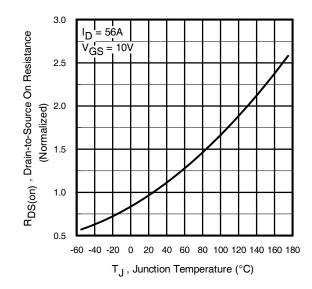


Fig 8. Maximum Safe Operating Area

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**Fig 9.** Maximum Drain Current Vs. Case Temperature

**Fig 10.** Normalized On-Resistance Vs. Temperature

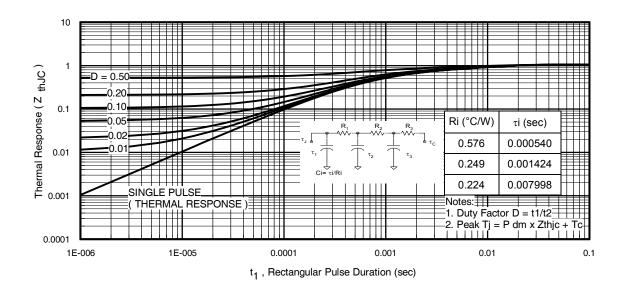


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Case



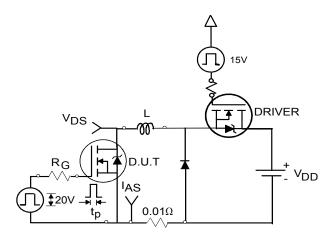


Fig 12a. Unclamped Inductive Test Circuit

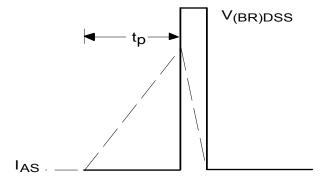


Fig 12b. Unclamped Inductive Waveforms

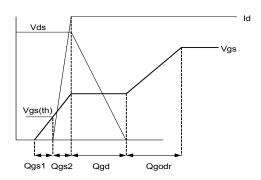


Fig 13a. Gate Charge Waveform

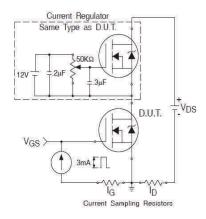
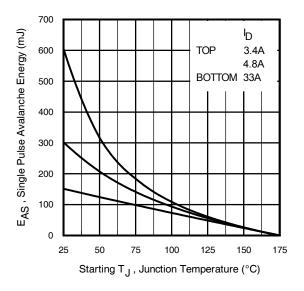


Fig 13b. Gate Charge Test Circuit



**Fig 12c.** Maximum Avalanche Energy vs. Drain Current

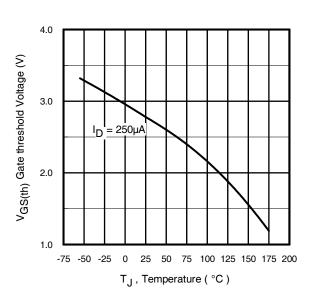


Fig 14. Threshold Voltage Vs. Temperature



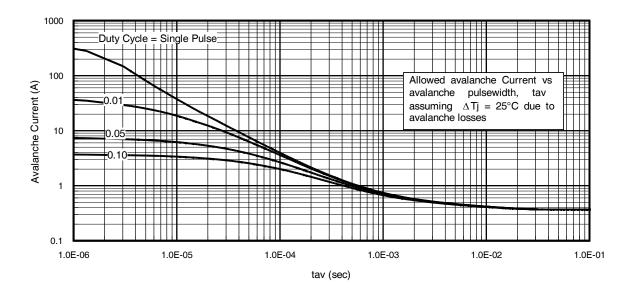
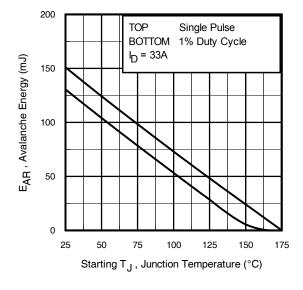


Fig 15. Typical Avalanche Current Vs. Pulse width



**Fig 16.** Maximum Avalanche Energy Vs. Temperature

## Notes on Repetitive Avalanche Curves , Figures 15, 16:

(For further info, see AN-1005 at www.infineon.com)

- Avalanche failures assumption:
   Purely a thermal phenomenon and failure occurs at a temperature far in excess of T<sub>imax</sub>. This is validated for every part type.
- 2. Safe operation in Avalanche is allowed as long as  $T_{jmax}$  is not exceeded.
- 3. Equation below based on circuit and waveforms shown in Figures 12a, 12b.
- 4. PD (ave) = Average power dissipation per single avalanche pulse.
- BV = Rated breakdown voltage (1.3 factor accounts for voltage increase during avalanche).
- 6. Iav = Allowable avalanche current.
- 7.  $\Delta T$  = Allowable rise in junction temperature, not to exceed  $T_{jmax}$  (assumed as 25°C in Figure 15, 16).

tav = Average time in avalanche.

D = Duty cycle in avalanche = tav ·f

ZthJC(D, tav) = Transient thermal resistance, see Figures 13)

$$\begin{split} P_{D \; (ave)} &= 1/2 \; (\; 1.3 \cdot BV \cdot I_{av}) = \Delta T / \; Z_{thJC} \\ I_{av} &= 2\Delta T / \; [1.3 \cdot BV \cdot Z_{th}] \\ E_{AS \; (AR)} &= P_{D \; (ave)} \cdot t_{av} \end{split}$$

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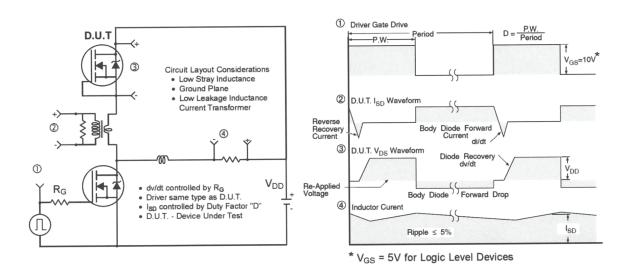


Fig 17. Peak Diode Recovery dv/dt Test Circuit for N-Channel HEXFET® Power MOSFETs

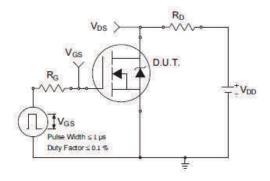


Fig 18a. Switching Time Test Circuit

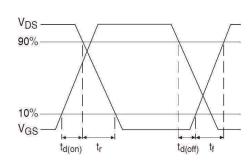
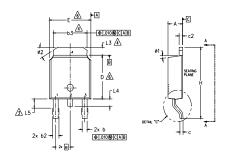


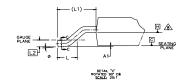
Fig 18b. Switching Time Waveforms

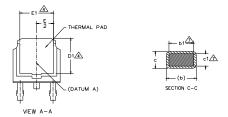


# D-Pak (TO-252AA) Package Outline (Dimensions are shown in millimeters (inches))









#### NOTES:

- 1.- DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- 1 LEAD DIMENSION UNCONTROLLED IN L5.
- A- DIMENSION D1, E1, L3 & b3 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.
- 5.— SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- \_\_\_ DIMENSION D & E DO NOT INCLUDE MOLD FLASH. MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- A- DIMENSION 61 & c1 APPLIED TO BASE METAL ONLY.
- ♠ DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-252AA.

S Y M B         DIMENSIONS         N O T E           M B B B B B B B B B B B B B B B B B B B							
B O L MINLIMETERS         INCHES         T E S E S E S E S E S E S E S E S E S E		DIMENSIONS					
A 2.18 2.39 .086 .094 A1 - 0.13005 b 0.64 0.89 .025 .035 b1 0.65 0.79 .025 .031 7 b2 0.76 1.14 .030 .045 b3 4.95 5.46 .195 .215 4 c 0.46 0.61 .018 .022 7 c2 0.46 0.89 .018 .035 D 5.97 6.22 .235 .245 6 D1 5.21205 - 4 E 6.35 6.73 .250 .265 6 E1 4.32170 - 4 E 6.35 6.73 .250 .265 6 E1 4.32170 - 4 E 2.29 BSC .090 BSC H 9.40 10.41 .370 .410 L 1.40 1.78 .055 .070 L1 2.74 BSC .108 REF. L2 0.51 BSC .020 BSC L3 0.89 1.27 .035 .050 4 L4102040 L5 1.14 1.52 .045 .060 3 Ø 0° 10° 0° 10° Ø1 0° 15° 0° 15°	В	MILLIM	ETERS	INC	HES	Ť	
A1         -         0.13         -         .005           b         0.64         0.89         .025         .035           b1         0.65         0.79         .025         .031         7           b2         0.76         1.14         .030         .045           b3         4.95         5.46         .195         .215         4           c         0.46         0.61         .018         .024         7           c2         0.46         0.89         .018         .035         6           D         5.97         6.22         .235         .245         6           D1         5.21         -         .205         -         4           E         6.35         6.73         .250         .265         6           E1         4.32         -         .170         -         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.40         1.78         .055         .070           L1         2.74         BSC         .108         REF.		MIN.	MAX.	MIN.	MAX.	E S	
b         0.64         0.89         .025         .035           b1         0.65         0.79         .025         .031         7           b2         0.76         1.14         .030         .045           b3         4.95         5.46         .195         .215         4           c         0.46         0.61         .018         .024         7           c1         0.41         0.56         .016         .022         7           c2         0.46         0.89         .018         .035           D         5.97         6.22         .235         .245         6           D1         5.21         -         .205         -         4           E         6.35         6.73         .250         .265         6           E1         4.32         -         .170         -         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.140         1.78         .055         .070           L1         2.74         BSC         .108         REF. <tr< td=""><td>Α</td><td>2.18</td><td>2.39</td><td>.086</td><td>.094</td><td></td></tr<>	Α	2.18	2.39	.086	.094		
b1         0.65         0.79         .025         .031         7           b2         0.76         1.14         .030         .045           b3         4.95         5.46         .195         .215         4           c         0.46         0.61         .018         .024         7           c2         0.46         0.89         .018         .035         6           D         5.97         6.22         .235         .245         6           D1         5.21         —         .205         —         4           E         6.35         6.73         .250         .265         6           E1         4.32         —         .170         —         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.140         1.78         .055         .070           L1         2.74         BSC         .108         REF.           L2         0.51         BSC         .020         BSC           L3         0.89         1.27         .035         .050         4 <td>A1</td> <td>-</td> <td>0.13</td> <td>-</td> <td>.005</td> <td></td>	A1	-	0.13	-	.005		
b2         0.76         1.14         0.30         0.045           b3         4.95         5.46         .195         .215         4           c         0.46         0.61         .018         .024         7           c1         0.41         0.56         .016         .022         7           c2         0.46         0.89         .018         .035           D         5.97         6.22         .235         .245         6           D1         5.21         -         .205         -         4           E         6.35         6.73         .250         .265         6           E1         4.32         -         .170         -         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.40         1.78         .055         .070           L1         2.74         BSC         .108         REF.           L2         0.51         BSC         .020         BSC           L3         0.89         1.27         .035         .050         4	b	0.64	0.89	.025	.035		
b3	ь1	0.65	0.79	.025	.031	7	
c         0.46         0.61         .018         .024           c1         0.41         0.56         .016         .022         7           c2         0.46         0.89         .018         .035         6           D         5.97         6.22         .235         .245         6           D1         5.21         -         .205         -         4           E         6.35         6.73         .250         .265         6           E1         4.32         -         .170         -         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.40         1.78         .055         .070           L1         2.74         BSC         .108         REF.           L2         0.51         BSC         .020         BSC           L3         0.89         1.27         .035         .050         4           L4         -         1.02         -         .040           L5         1.14         1.52         .045         .060         3	b2	0.76	1.14	.030	.045		
c1         0.41         0.56         .016         .022         7           c2         0.46         0.89         .018         .035         6           D         5.97         6.22         .235         .245         6           D1         5.21         -         .205         -         4           E         6.35         .250         .265         6           E1         4.32         -         .170         -         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.40         1.78         .055         .070           L1         2.74         BSC         .108         REF.           L2         0.51         BSC         .020         BSC           L3         0.89         1.27         .035         .050         4           L4         -         1.02         -         .040           L5         1.14         1.52         .045         .060         3           Ø         0°         10°         0°         10°         10°           Ø	b3	4.95	5.46	.195	.215	4	
c2         0.46         0.89         .018         .035           D         5.97         6.22         .235         .245         6           D1         5.21         -         .205         -         4           E         6.35         6.73         .250         .265         6           E1         4.32         -         .170         -         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.40         1.78         .055         .070           L1         2.74         BSC         .108         REF.           L2         0.51         BSC         .020         BSC           L3         0.89         1.27         .035         .050         4           L4         -         1.02         -         .040           L5         1.14         1.52         .045         .060         3           Ø         0°         10°         0°         10°           Ø         0°         15°         0°         15°	С	0.46	0.61	.018	.024		
D   5.97   6.22   .235   .245   6	c1	0.41	0.56	.016	.022	7	
D1	c2	0.46	0.89	.018	.035		
E 6.35 6.73 .250 .265 6 E1 4.32170 - 4 e 2.29 BSC .090 BSC H 9.40 10.41 .370 .410 L 1.40 1.78 .055 .070 L1 2.74 BSC .108 REF. L2 0.51 BSC .020 BSC L3 0.89 1.27 .035 .050 4 L4 - 1.02040 L5 1.14 1.52 .045 .060 3 ø 0° 10° 0° 10° 0° 10° ø1 0° 15° 0° 15°	D	5.97	6.22	.235	.245	6	
E1         4.32         -         .170         -         4           e         2.29         BSC         .090         BSC           H         9.40         10.41         .370         .410           L         1.40         1.78         .055         .070           L1         2.74         BSC         .108         REF.           L2         0.51         BSC         .020         BSC           L3         0.89         1.27         .035         .050         4           L4         -         1.02         -         .040           L5         1.14         1.52         .045         .060         3           Ø         0°         10°         0°         10°           Ø1         0°         15°         0°         15°	D1	5.21	-	.205	-	4	
e         2.29 BSC         .090 BSC           H         9.40         10.41         .370         .410           L         1.40         1.78         .055         .070           L1         2.74 BSC         .108 REF.           L2         0.51 BSC         .020 BSC           L3         0.89         1.27         .035         .050         4           L4         -         1.02         -         .040         L5         1.14         1.52         .045         .060         3           Ø         0°         10°         0°         10°         0°         15°           Ø         0°         15°         0°         15°         0°         15°	Ε	6.35	6.73	.250	.265	6	
H   9.40   10.41   .370   .410	E1	4.32	-	.170	-	4	
L 1.40 1.78 .055 .070 L1 2.74 BSC .108 REF. L2 0.51 BSC .020 BSC L3 0.89 1.27 .035 .050 4 L4 - 1.02040 L5 1.14 1.52 .045 .060 3 Ø 0° 10° 0° 10° 0° 10° Ø1 0° 15° 0° 15°	е	2.29	BSC	.090	BSC		
L1	Н	9.40	10.41	.370	.410		
L2         0.51 BSC         .020 BSC           L3         0.89         1.27         .035         .050         4           L4         -         1.02         -         .040         .045         .060         3           Ø         0°         10°         0°         10°         9         15°         15°         15°	L	1.40	1.78	.055	.070		
L3 0.89 1.27 .035 .050 4 L4 - 1.02040 L5 1.14 1.52 .045 .060 3 Ø 0° 10° 0° 10° Ø1 0° 15° 0° 15°	L1	2.74	BSC	.108	REF.		
L4         -         1.02         -         .040           L5         1.14         1.52         .045         .060         3           Ø         0°         10°         0°         10°           Ø1         0°         15°         0°         15°	L2	0.51	BSC	.020	BSC		
L5 1.14 1.52 .045 .060 3 ø 0° 10° 0° 10° ø1 0° 15° 0° 15°	L3	0.89	1.27	.035	.050	4	
ø     0°     10°     0°     10°       ø     0°     15°     0°     15°	L4	-	1.02	-	.040		
ø1 0° 15° 0° 15°	L5	1.14	1.52	.045	.060	3	
	ø	0.	10°	0,	10°		
ø2   25°   35°   25°   35°	ø1	0,	15*	0,	15*		
	ø2	25*	35°	25*	35*		

#### LEAD ASSIGNMENTS

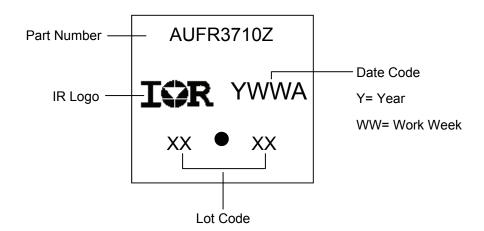
## **HEXFET**

- 1.- GATE
- 2.- DRAIN
- 3.- SOURCE 4.- DRAIN

#### IGBT & CoPAK

- 1.- GATE
- 2.- COLLECTOR
- 3.- EMITTER
- 4.- COLLECTOR

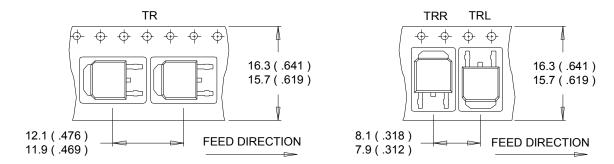
## D-Pak (TO-252AA) Part Marking Information



Note: For the most current drawing please refer to IR website at http://www.irf.com/package/

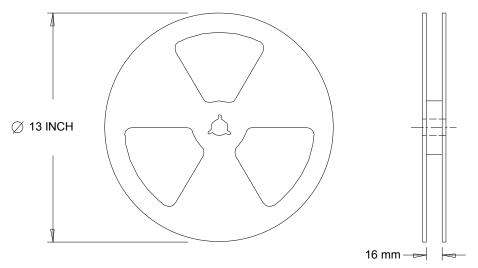


# D-Pak (TO-252AA) Tape & Reel Information (Dimensions are shown in millimeters (inches))



#### NOTES:

- 1. CONTROLLING DIMENSION: MILLIMETER.
- 2. ALL DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
- 3. OUTLINE CONFORMS TO EIA-481 & EIA-541.



# NOTES:

1. OUTLINE CONFORMS TO EIA-481.

Note: For the most current drawing please refer to IR website at <a href="http://www.irf.com/package/">http://www.irf.com/package/</a>



#### **Qualification Information**

		Automotive				
			(per AEC-Q101)			
Qualification Level  Comments: This part number(s) passed Automotive qualification Industrial and Consumer qualification level is granted by extension Automotive level.						
Moisture Sensitivity Level D-Pak MSL1						
	Machine Madel	Class M4 <sup>†</sup>				
	Machine Model	AEC-Q101-002				
FOR	Liver on Dady Madel		Class H1C <sup>†</sup>			
ESD	Human Body Model	AEC-Q101-001				
Charged Device Model		Class C3 <sup>†</sup>				
		AEC-Q101-005				
RoHS Co	mpliant	Yes				

<sup>†</sup> Highest passing voltage.

## **Revision History**

Date	Comments		
11/23/2015	Updated datasheet with corporate template		
11/23/2013	Corrected ordering table on page 1.		

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